CD2003GP/GB FM/AM RADIO IC

1. Overview

The CD2003GP/GB is a monolithic IC designed for use as a FM/AM radio system.

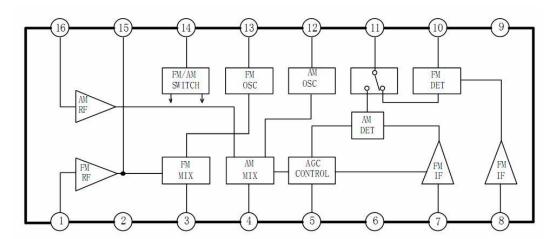
Combined with audio power amplifier IC, a suitable FM/AM radio can be constituted. Its

features are:

- No need for FM IFT, AM IFT, and FM detector coil
- Adjustment free for FM detector circuit
- Package: DIP16/SOP16

2 Nock Diagram And Pin Descriptions

2. 1. Block Diagram



2. 2. Pin Descriptions

Version: 2008-07-A

PIN	Symbol	Function	PIN	Symbol	Function	
1	IN_{FMR}	FM RF Input	9	GND_{OUT}	Output Ground	
2	GND_{IN}	Input Ground	10	QUAD	QUAD	
3	OUT_{FMM}	FM Mixer Output	11	OUT_{DET}	Detector Output	
4	OUT _{AMM}	AM Mixer Output	12	OSC _{AM}	AM Oscillation	
5	AGC	AGC Control	13	OSC_{FM}	FM Oscillation	
6	V_{CC}	Supply Voltage	14	SW	AM/FM Switch	
7	IN _{AMI}	AM IF Input	15	TUN_{FM}	FM Tuner	
8	IN _{FMI}	FM IF Input	16	IN _{AMR}	AM RF Input	



3. Electrical Characteristics

3.1. Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Conditions	Value	Unit	
Supply Voltage	V_{CC}		8	V	
Power	D	DIP16	750		
Dissipation	$P_{\rm D}$	SOP16	350	mW	
Operating	т		- 25 ~ 75	$^{\circ}$	
Temperature	T_{amb}		- 23 ~ 73	C	
Storage	т		- 55 ~ 150	$^{\circ}$	
Temperature	T_{stg}		- 55 ~ 150	C	

NOTE: Derated above T_{amb} =25 °C in the proportion of 6mW/°C for CD2003GP and of 2.8mW/°C for CD2003GB.

3.2. Electrical Characteristics

Unless otherwise specified, $T_{amb}=25\,^{\circ}\text{C}$, $V_{CC}=3V$

F/E: f=98MHz, $f_m=1kHz$

FM IF: f=10.7MHz, $\triangle f=\pm 22.5kHz$, $f_m=1kHz$

AM: f=1MHz, MOD=30%, $f_m=1kHz$

Parameter	Symbol	Test Conditions		Unit			
Parameter	Symbol	Test Conditions	Min	Тур	Max	UIII	
Supply	T	FM mode, V _{in} =0	5.0	10.5	16.5	A	
Current	I_{CCQ}	AM mode, V _{in} =0	3.5	5.0	8.0	mA	
F/E							
Quiescent	0	S/N=30dB		2		uV	
Sensitivity	Qs	S/N=SUUD		2		u v	
Input							
Limiting	$V_{IN(\;LIM)}$	Vo 为-3 dB		2		uV	
Sensitivity							
Local OSC	V _{STOP} (FM	$V_{in}=0$		1.2		V	
Stop Voltage	▼ STOP(FM	V in-U		1.2		v	
Local OSC	V_{OSC}	$f_{OSC}=108MHZ$	160	240	320	mV	
Voltage	V OSC	10SC-100M11Z					
FM IF							
Input							
Limiting	$V_{IN(\ LIM)}$	Vo 为-3dB	63	112	200	uV	
Sensitivity							
Detector							
Output	V_{OD}	V _{in} =80dBu EMF	75		130	mV	
Voltage							
Signal to	S/N	V _{in} =80dBu EMF		62		dB	
Noise Ratio	D/1 N	v _{in} =oodbu EMT		02		uD	

To be continued

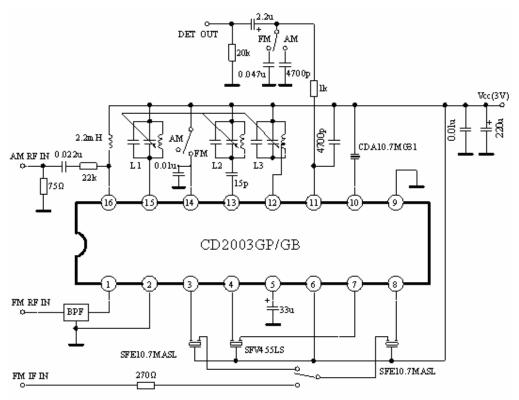


continued

Danamatan	Cymbol	Test Con	ditions		Unit			
Parameter	Symbol	Test Con	ditions	Min	Тур	Max	UIII	
Total								
Harmonic	THD	V _{in} =80dBu	EMF		0.4		%	
Distortion								
AM Rejection	AMR	V. =20dPn	EMF		33		dB	
Ratio	AMK	V _{in} =80dBu	EIVIF		33		uБ	
AM								
Detector								
Output	V_{OD1}	V _{in} =27dBu	EMF	15		50	mV	
Voltage 1								
Detector								
Output	V_{OD2}	V _{in} =60dBu	EMF	40	60	100	mV	
Voltage 2								
Signal to	S/N	V _{in} =60dBu	EMF		43		dB	
Noise Ratio	3/11	v _{in} -ooubu	EWII		43		uБ	
Total								
Harmonic	THD	V _{in} =60dBu	EMF		1		%	
Distortion								
Local OSC	V	W _0			1.6		V	
Stop Voltage	V_{STO} (AM)	v in=U			1.0		V	

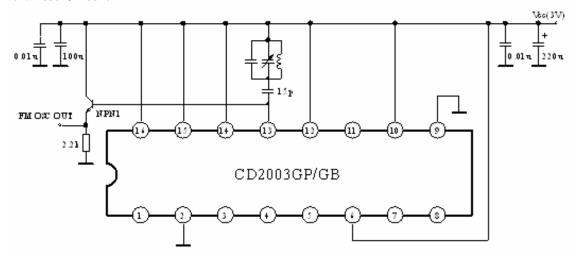
4. Test Circuit

4.1. Test Circuit 1





4.2. Test Circuit 2

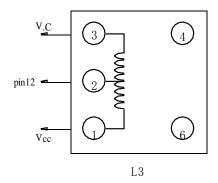


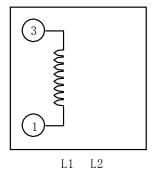
4.3 Note

Coil Data (Test Circuit)

	Test						Turns				
Coil No.	Freque	L	0.	$Q_{\rm O} \begin{vmatrix} C_{\rm O} \\ (pF) \end{vmatrix}$						Wire	Reference
Con No.	ncy	(uH	Q ₀		1-2	2-3	1-3	1-4	4-6	(mm)	Reference
	(HZ))									
L1:	100M		100					2.25		0.5	0258-0000
FM RF	TOOM		100					2.23		0.5	-021 (注)
L2:	100M		100				1.75			0.5	0258-000
FM OSC	TOOM		100				1.73			0.5	-020 (注)
L3:	796K	268	125		14	86				0.06	2157-2239
AM OSC	190 K	208	123		14	00				0.00	-213A (注)

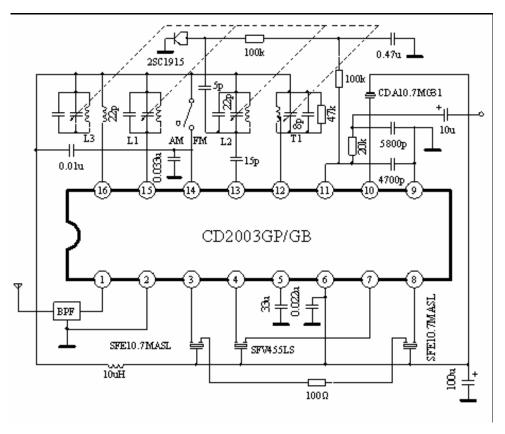
NOTE: SUMIDA ELECTRIC CO., LTD





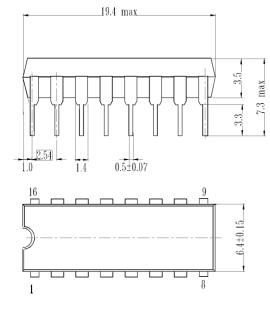


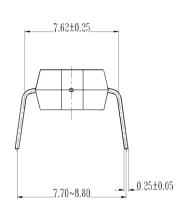
5. Application Circuit



6. Package Outline

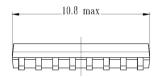
6.1 DIP16

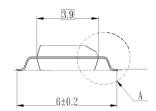


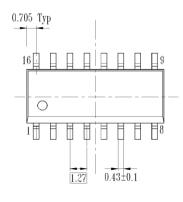


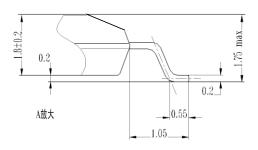


6.2 SOP16











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